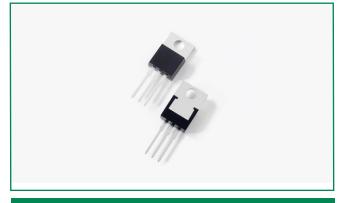
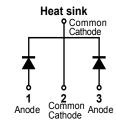
DST20100C

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## Pin out



#### Description

The Littelfuse DST series Ultra Low V<sub>F</sub> Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage and low V<sub>F</sub> products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

### Features

- Ultra low forward voltage drop
- High frequency operation
- High junction
   temperature capability
- Guard ring for enhanced ruggedness and long term reliability
- Common cathode configuration in TO-220AB package

Po

RoHS

• Lead-free and RoHS compliant

#### Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings				
Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V <sub>RWM</sub>	-	100	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>c</sub> =120°C rectangular wave form	10 (per leg)	A
			20 (total device)	
Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

Electrical Characteristics					
Parameters	Symbol	Test Conditions	Тур	Max	Unit
Forward Voltage Drop (per leg) *	V <sub>F1</sub>	@5A, Pulse, T <sub>J</sub> = 25°C	0.54	0.55	- V
		@10A, Pulse, T <sub>J</sub> = 25°C	0.69	0.75	
	V <sub>F2</sub>	@5A, Pulse, T <sub>J</sub> = 125°C	0.48	0.53	
		@10A, Pulse, T <sub>J</sub> = 125°C	0.59	0.70	
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_{R} = rated V_{R}T_{J} = 25 \text{ °C}$	18	300	μA
	I <sub>R2</sub>	$@V_{R} = rated V_{R}T_{J} = 100 \text{ °C}$	-	12	mA
	I <sub>R3</sub>	$@V_{R} = rated V_{R}T_{J} = 125 \text{ °C}$	7.8	36	
Junction Capacitance (per leg)	C <sub>T</sub>	$@V_{_{ m R}} = 5V, T_{_{ m C}} = 25 \ ^{\circ}C, f_{_{ m SIG}} = 1MHz$	462	-	рF

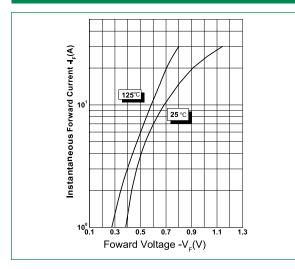
\* Pulse Width < 300µs, Duty Cycle <2%

# **Maximum Ratings**

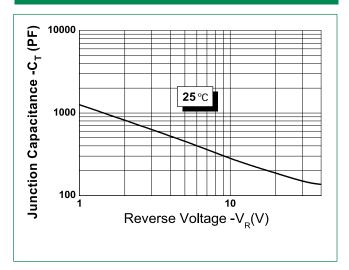
#### **Thermal-Mechanical Specifications**

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	TJ		-55 to +150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C
Thermal Resistance Junction to Case (per leg)	R <sub>ejc</sub>	DC operation	2.8	°C/W
Approximate Weight	wt		2	g
Case Style		TO-220AB		

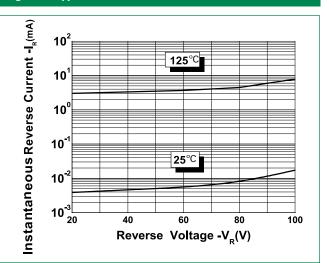
# Figure 1: Typical Forward Characteristics



#### Figure 3: Typical Junction Capacitance

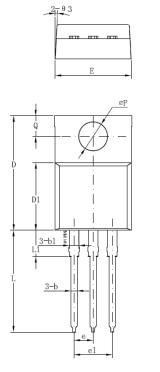


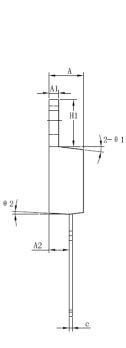
## Figure 2: Typical Reverse Characteristics





## Dimensions-TO-220AB

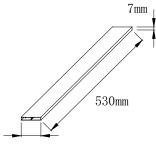




Symbol	Millimeters		
	Min	Max	
Α	3.56	4.83	
A1	0.51	1.40	
A2	2.03	2.92	
b	0.38	1.02	
b1	1.14	1.78	
C	0.31*	0.61	
D	14.22	16.51	
D1	8.38	9.15*	
E	9.65	10.67	
е	2.54	-	
e1	4.98*	-	
H1	5.84	6.86	
L	12.70	14.73	
L1	-	6.35	
ØP	3.53	4.09	
Q	2.54	3.43	

Footnote \*: The spec. does not comply with JEDEC spec.





32mm

#### Part Numbering and Marking System



DST	= DeviceType
20	= Forward Current (20A)
100	= Reverse Voltage (100V)
С	= Configuration
LF	= Littelfuse
YY	=Year
WW	=Week
L	= Lot Number

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